

Technical Data Green Products

Data Sheet N1023, Rev. -

Power Surface Mount Schottky Rectifier (80V/100V, 60Amp)

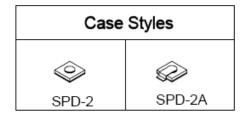
Applications:

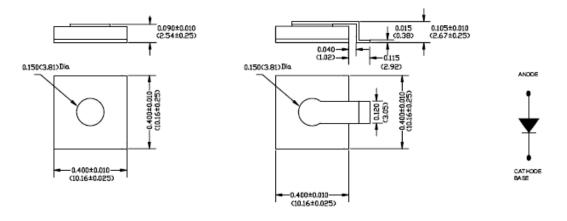
- Switching power supply
- Converters
- · Reverse battery protection
- Redundant power subsystems
- Many other high current AC/DC power supplies

Features:

- 175 °C T_J operation
- Low forward voltage drop
- · High surge capacities
- High frequency operation
- Guaranteed reverse avalanche capability
- Low profile surface mount package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm/ Inches





SPD-2 SPD-2A

Suffix "R" Denotes Reversed Polarity

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Maximum Ratings:

Characteristics	Symbol	Condition		Max.	Units
Peak Inverse Voltage	V_{RWM}	-	80	(63SPB080/A)	V
			100	(63SPB100/A)	
Max. Average Forward	I _{F(AV)}	50% duty cycle, rectangular wave form		60	Α
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	860		А
Non-Repetitive Avalanche Energy(per leg)	E _{AS}	T_J =25 °C , I_{AS} =0.75A, L=40 mH	11.25		mJ
Repetitive Avalanche Current(per leg)	I _{AR}	I_{AS} decaying linearly to 0 in 1 μ sec Frequency limited by T_J max. V_A =1.5 \times V_R		0.75	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop*	V_{F1}	@ 60A, Pulse, T _J = 25 °C	0.87	V
	V_{F2}	@ 60A, Pulse, T _J = 125 °C	0.72	V
Max. Reverse Current (per	I _{R1}	@V _R = rated V _R	1.0	mA
leg) *		T _J = 25 °C		
	I _{R2}	$@V_R = rated V_R$	24.0	mA
		T _J = 125 °C		
Max. Junction Capacitance	CJ	$@V_R = 5V, T_C = 25 ^{\circ}C$	1500	pF
(per leg)		f _{SIG} = 1MHz		
Max. Voltage Rated of	dv/dt	-	10,000	V/μs
Change				

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	T_J	-	-55 to +175	°C
Max. Storage Temperature	T _{stg}	-	-55 to +175	°C
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	0.37	°C/W
Case Style	SPD-2/A			

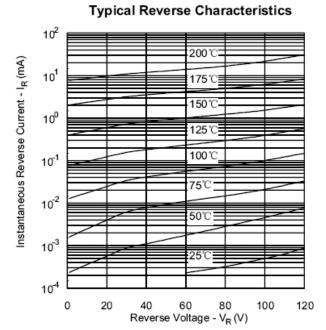
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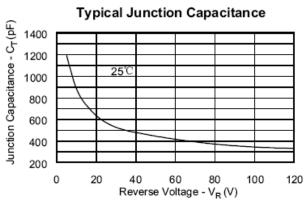
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Typical Forward Characteristics 10² **200**℃ 10¹ Instantaneous Forward Current - I_F(A) 10⁰ 25℃ 10⁻¹ 0.2 0.1 0.3 0.4 0.5 0.6 0.7 8.0 Forward Voltage Drop - V_F(V)





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